

HiPerFAST™ IGBT

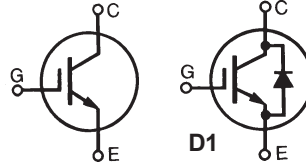
ISOPLUS247™

B2-Class High Speed IGBTs

(Electrically Isolated Back Surface)

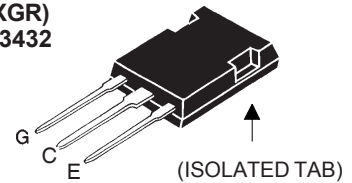
IXGR 60N60B2
IXGR 60N60B2D1

V_{CES} = 600 V
 I_{C25} = 75 A
 $V_{CE(sat)}$ = 2.0 V
 $t_{fi(typ)}$ = 100 ns



| Symbol | Test Conditions | Maximum Ratings | |
|-------------------------------|---|-----------------|------------------|
| V_{CES} | $T_J = 25^\circ\text{C}$ to 150°C | 600 | V |
| V_{CGR} | $T_J = 25^\circ\text{C}$ to 150°C ; $R_{GE} = 1\ \text{M}\Omega$ | 600 | V |
| V_{GES} | Continuous | ± 20 | V |
| V_{GEM} | Transient | ± 30 | V |
| I_{C25} | $T_C = 25^\circ\text{C}$ (limited by leads) | 75 | A |
| I_{C110} | $T_C = 110^\circ\text{C}$ | 47 | A |
| I_{CM} | $T_C = 25^\circ\text{C}$, 1 ms | 300 | A |
| SSOA (RBSOA) | $V_{GE} = 15\ \text{V}$, $T_{VJ} = 125^\circ\text{C}$, $R_G = 10\ \Omega$ Clamped inductive load @ $V_{CE} \leq 600\ \text{V}$ | $I_{CM} = 150$ | A |
| P_C | $T_C = 25^\circ\text{C}$ | 250 | W |
| T_J | | -55 ... +150 | $^\circ\text{C}$ |
| T_{JM} | | 150 | $^\circ\text{C}$ |
| T_{stg} | | -55 ... +150 | $^\circ\text{C}$ |
| V_{ISOL} | 50/60 Hz, RMS, $t = 1\ \text{m}$ | 2500 | V |
| Weight | | 5 | g |
| | Maximum lead temperature for soldering 1.6 mm (0.062 in.) from case for 10 s | 300 | $^\circ\text{C}$ |

PLUS247(IXGR)
E153432



G = Gate C = Collector
E = Emitter

Features

- DCB Isolated mounting tab
- Meets TO-247AD package Outline
- High current handling capability
- Latest generation HDMOS™ process
- MOS Gate turn-on - drive simplicity

Applications

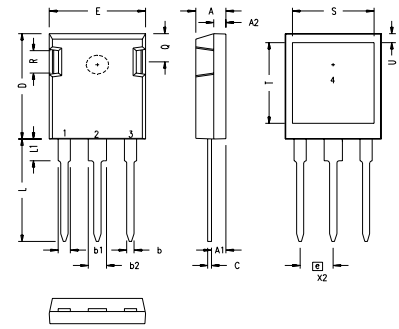
- Uninterruptible power supplies (UPS)
- Switched-mode and resonant-mode power supplies
- AC motor speed control
- DC servo and robot drives
- DC choppers

Advantages

- Easy assembly
- High power density
- Very fast switching speeds for high frequency applications

| Symbol | Test Conditions | Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified) | | |
|---------------|---|---|------|---------------------------|
| | | Min. | Typ. | Max. |
| $V_{GE(th)}$ | $I_C = 250\ \mu\text{A}$, $V_{CE} = V_{GE}$ | 3.0 | | 5.0 V |
| I_{CES} | $V_{CE} = V_{CES}$ $V_{GE} = 0\ \text{V}$ $T_J = 125^\circ\text{C}$ | | | 300 μA 5 mA |
| I_{GES} | $V_{CE} = 0\ \text{V}$, $V_{GE} = \pm 20\ \text{V}$ | | | $\pm 100\ \text{nA}$ |
| $V_{CE(sat)}$ | $I_C = 50\ \text{A}$, $V_{GE} = 15\ \text{V}$ Note 1 | | | 2.0 V |

| Symbol | Test Conditions | Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified) | | | |
|--------------|--|---|------|---------|----|
| | | Min. | Typ. | Max. | |
| g_{fs} | $I_C = 50\text{ A}; V_{CE} = 10\text{ V}$, Note 1 | 40 | 58 | S | |
| C_{ies} | $V_{CE} = 25\text{ V}, V_{GE} = 0\text{ V}, f = 1\text{ MHz}$ | | 3900 | pF | |
| C_{oes} | | | 340 | pF | |
| C_{res} | | | 100 | pF | |
| Q_g | $I_C = 50\text{ A}, V_{GE} = 15\text{ V}, V_{CE} = 0.5 V_{CES}$ | | 170 | nC | |
| Q_{ge} | | | 25 | nC | |
| Q_{gc} | | | 57 | nC | |
| $t_{d(on)}$ | Inductive load, $T_J = 25^\circ\text{C}$ $I_C = 50\text{ A}, V_{GE} = 15\text{ V}$ $V_{CE} = 400\text{ V}, R_G = R_{off} = 3.3\ \Omega$ | | 28 | ns | |
| t_{ri} | | | 30 | ns | |
| $t_{d(off)}$ | | | 160 | 270 | ns |
| t_{fi} | | | 100 | 170 | ns |
| E_{off} | | | 1.0 | 2.5 | mJ |
| $t_{d(on)}$ | Inductive load, $T_J = 125^\circ\text{C}$ $I_C = 50\text{ A}, V_{GE} = 15\text{ V}$ $V_{CE} = 400\text{ V}, R_G = R_{off} = 2.0\ \Omega$ | | 28 | ns | |
| t_{ri} | | | 36 | ns | |
| E_{on} | | | 1.5 | mJ | |
| $t_{d(off)}$ | | | 310 | ns | |
| t_{fi} | | | 240 | ns | |
| E_{off} | | 2.8 | mJ | | |
| R_{thJC} | | | 0.15 | 0.5 K/W | |
| R_{thCK} | | | | K/W | |

ISOPLUS 247 Outline


| SYM | INCHES | | MILLIMETERS | |
|-----|----------|------|-------------|-------|
| | MIN | MAX | MIN | MAX |
| A | .190 | .205 | 4.83 | 5.21 |
| A1 | .090 | .100 | 2.29 | 2.54 |
| A2 | .075 | .085 | 1.91 | 2.16 |
| b | .045 | .055 | 1.14 | 1.40 |
| b1 | .075 | .084 | 1.91 | 2.13 |
| b2 | .115 | .123 | 2.92 | 3.12 |
| C | .024 | .031 | 0.61 | 0.80 |
| D | .819 | .840 | 20.80 | 21.34 |
| E | .620 | .635 | 15.75 | 16.13 |
| e | .215 BSC | | 5.45 BSC | |
| L | .780 | .800 | 19.81 | 20.32 |
| L1 | .150 | .170 | 3.81 | 4.32 |
| Q | .220 | .244 | 5.59 | 6.20 |
| R | .170 | .190 | 4.32 | 4.83 |
| S | .520 | .540 | 13.21 | 13.72 |
| T | .620 | .640 | 15.75 | 16.26 |
| U | .065 | .080 | 1.65 | 2.03 |

- 1 - GATE
- 2 - DRAIN (COLLECTOR)
- 3 - SOURCE (EMITTER)
- 4 - NO CONNECTION

NOTE: This drawing will meet all dimensions requirement of JEDEC outline TO-247AD except screw hole.

Reverse Diode (FRED)

| Symbol | Test Conditions | Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified) | | |
|------------|---|---|------|----------|
| | | min. | typ. | max. |
| V_F | $I_F = 60\text{ A}, V_{GE} = 0\text{ V}$, Note 1 | | | 2.1 V |
| | | | | 1.4 V |
| I_{RM} | $I_F = 60\text{ A}, V_{GE} = 0\text{ V}, -di_F/dt = 100\text{ A}/\mu\text{s}$ $V_R = 100\text{ V}$ | | | 8.3 A |
| t_{rr} | $I_F = 1\text{ A}; -di/dt = 200\text{ A}/\text{ms}; V_R = 30\text{ V}$ | | 35 | ns |
| R_{thJC} | | | | 0.85 K/W |

Note 1: Pulse test, $t \leq 300\ \mu\text{s}$, duty cycle $\leq 2\%$

IXYS reserves the right to change limits, test conditions, and dimensions.

Fig. 1. Output Characteristics
@ 25 Deg. C

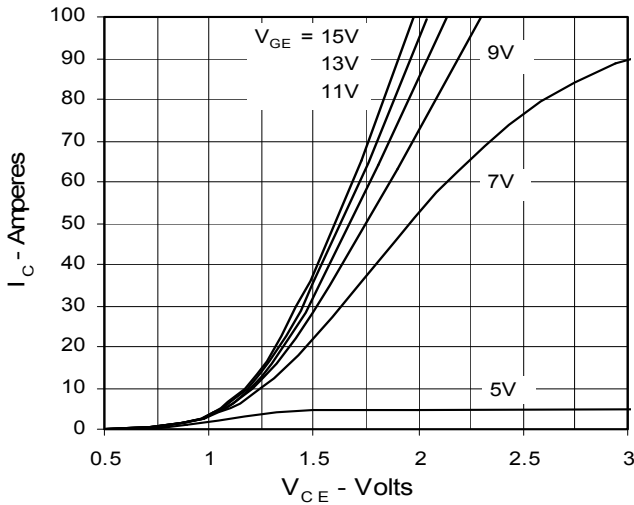


Fig. 2. Extended Output Characteristics
@ 25 deg. C

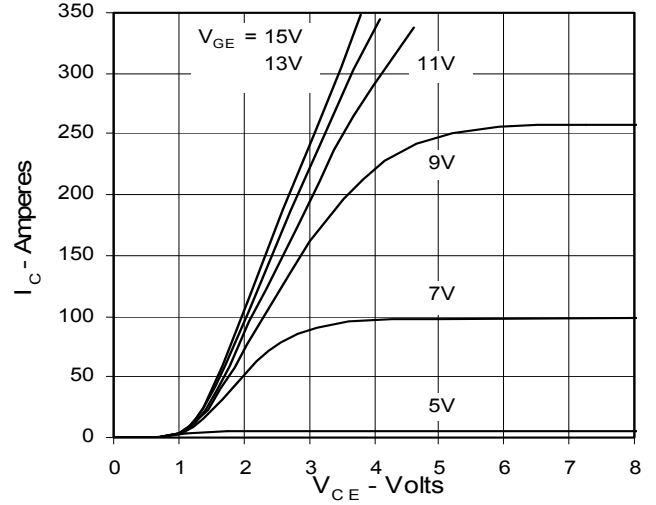


Fig. 3. Output Characteristics
@ 125 Deg. C

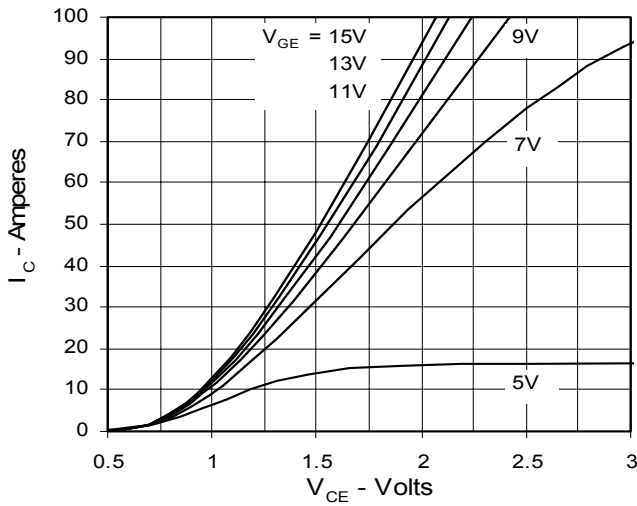


Fig. 4. Dependence of $V_{CE(sat)}$ on Temperature

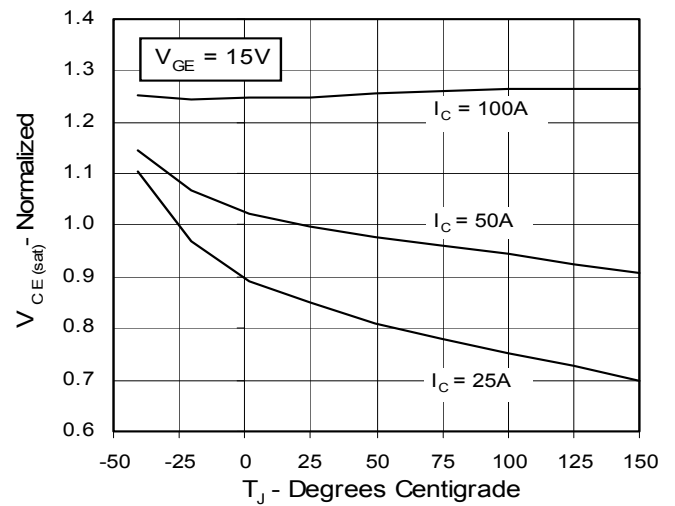


Fig. 5. Collector-to-Emitter Voltage vs. Gate-to-Emitter voltage

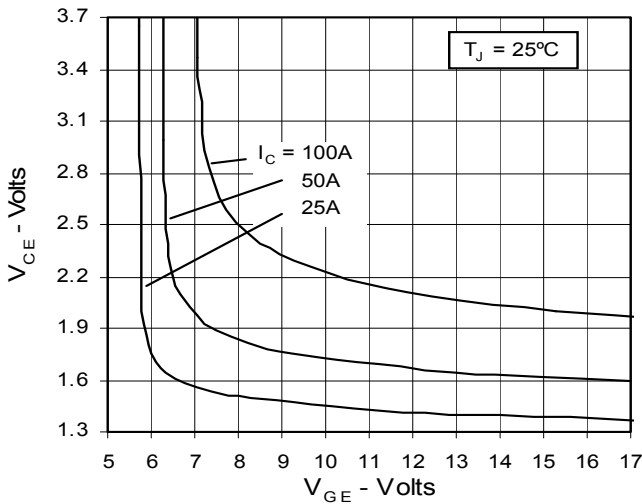


Fig. 6. Input Admittance

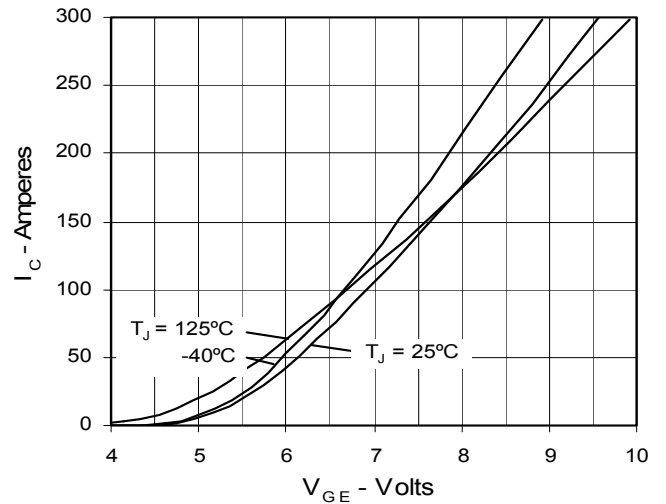


Fig. 7. Transconductance

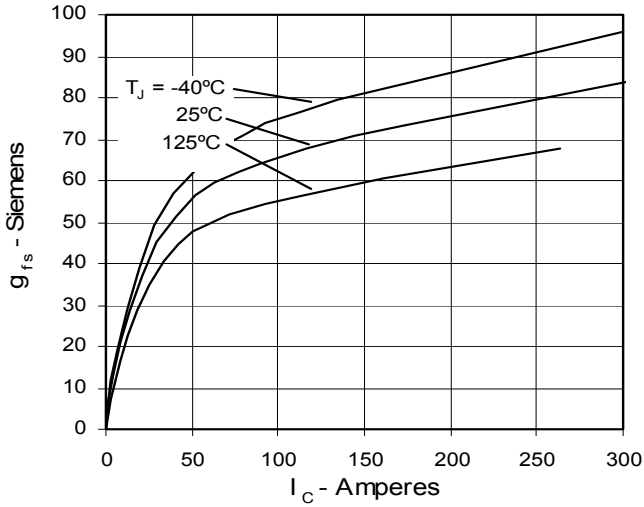


Fig. 8. Dependence of Turn-Off Energy on R_G

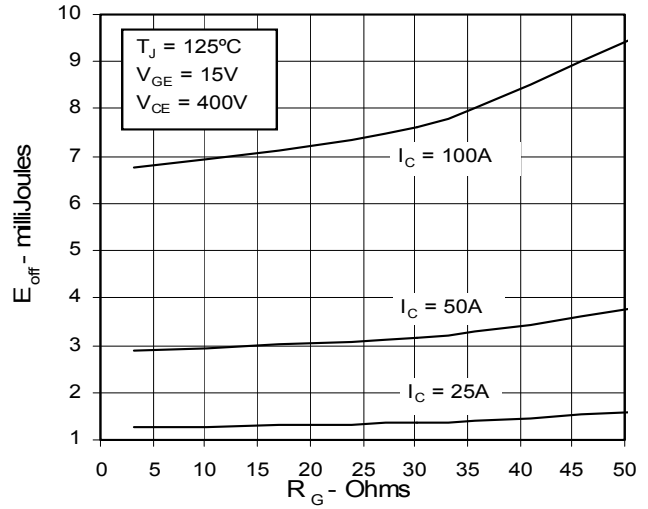


Fig. 9. Dependence of Turn-Off Energy on I_C

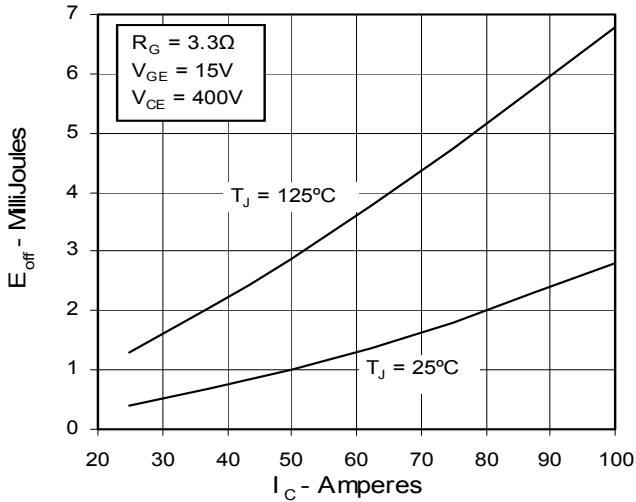


Fig. 10. Dependence of Turn-Off Energy on Temperature

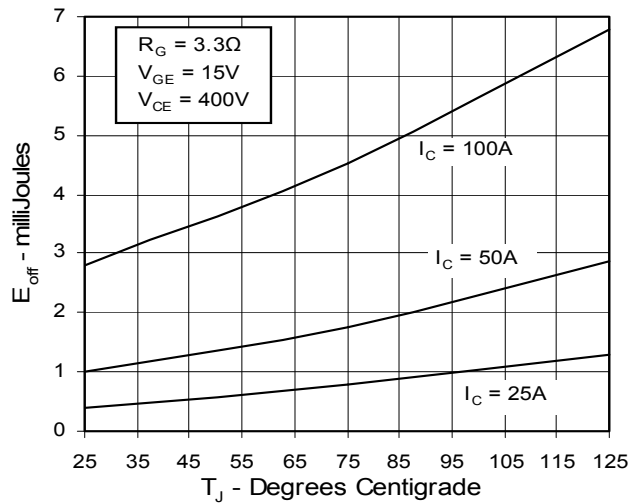


Fig. 11. Dependence of Turn-Off Switching Time on R_G

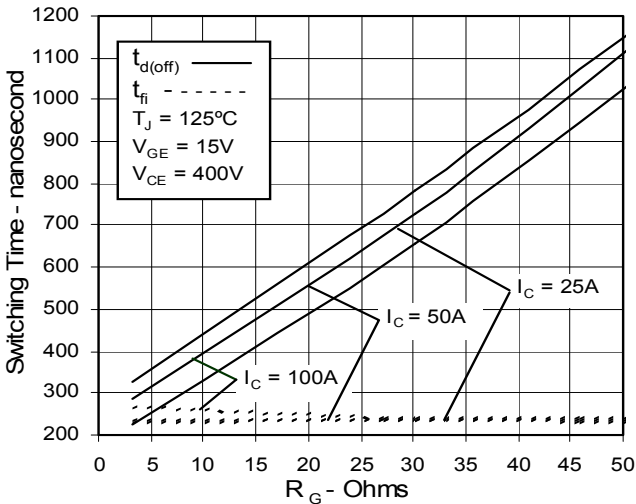


Fig. 12. Dependence of Turn-Off Switching Time on I_C

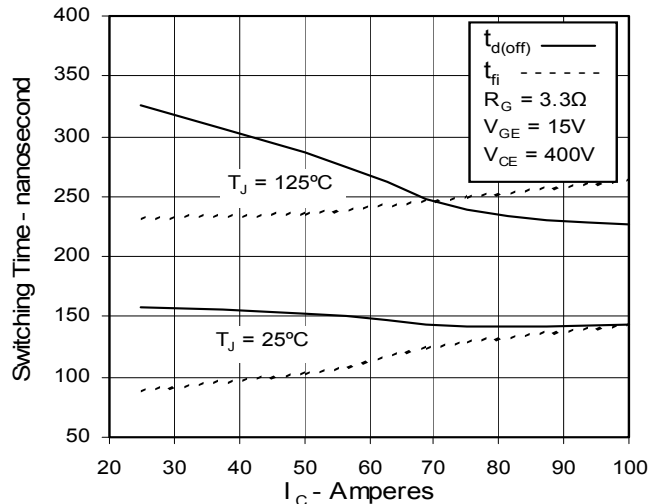


Fig. 13. Dependence of Turn-Off Switching Time on Temperature

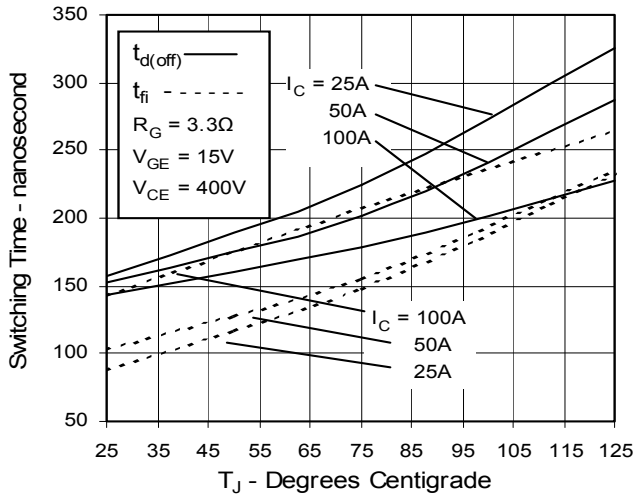


Fig. 14. Gate Charge

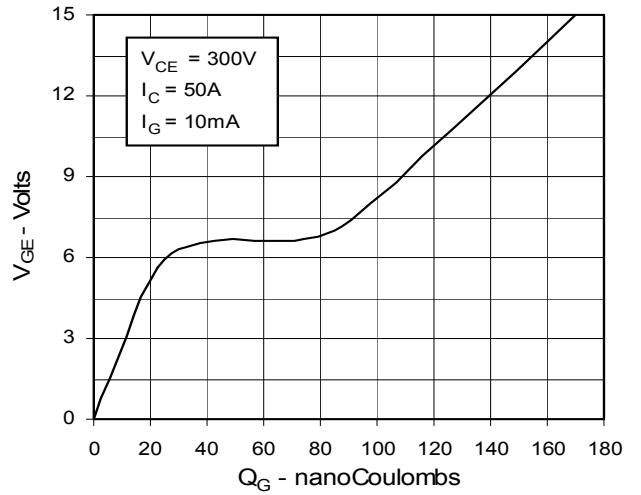


Fig. 15. Capacitance

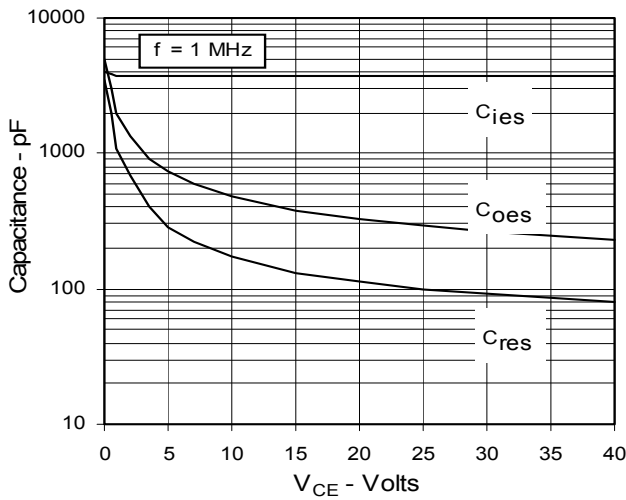
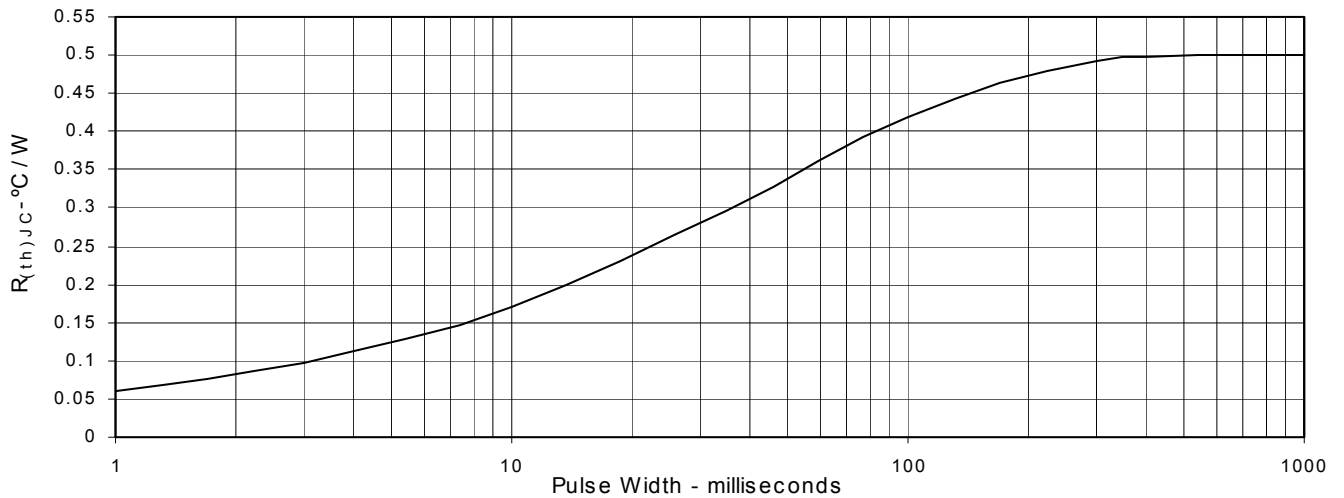


Fig. 13. Maximum Transient Thermal Resistance



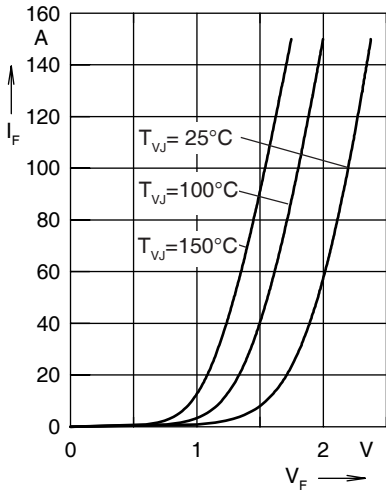


Fig. 17. Forward current I_F versus V_F

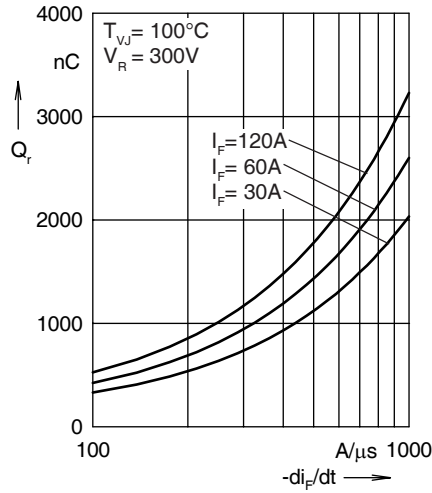


Fig. 18. Reverse recovery charge Q_r versus $-di_F/dt$

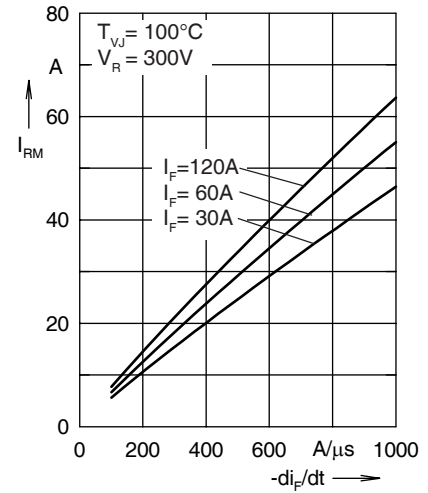


Fig. 19. Peak reverse current I_{RM} versus $-di_F/dt$

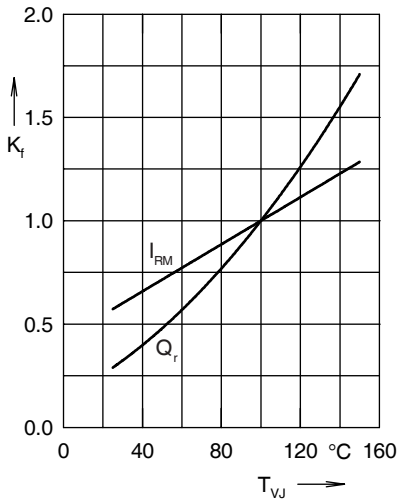


Fig. 20. Dynamic parameters Q_r , I_{RM} versus T_{VJ}

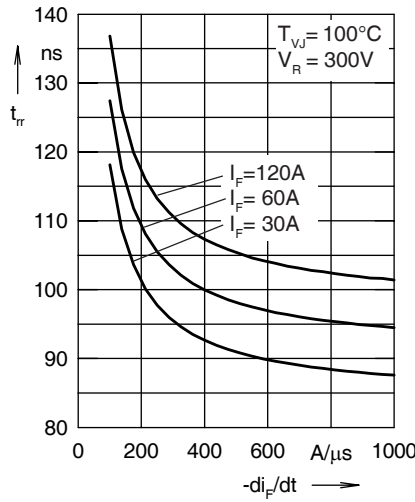


Fig. 21. Recovery time t_{tr} versus $-di_F/dt$

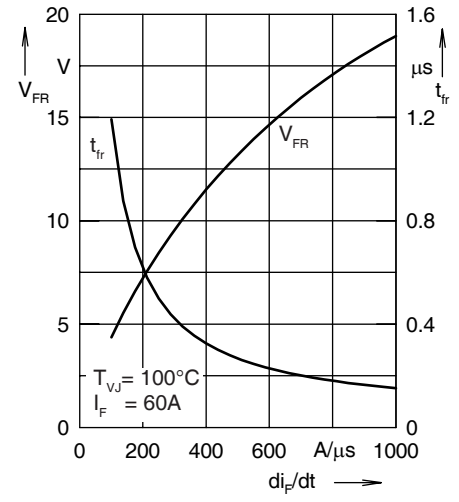


Fig. 22. Peak forward voltage V_{FR} and t_{tr} versus di_F/dt

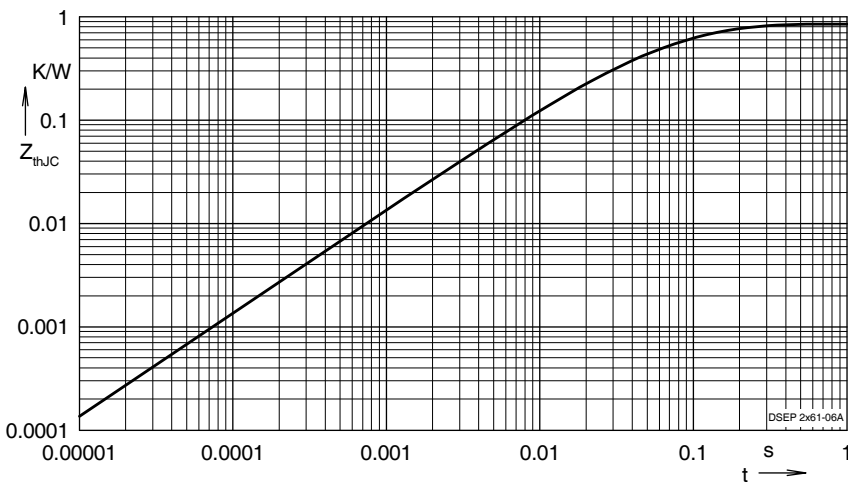


Fig. 23. Transient thermal resistance junction to case

Constants for Z_{thJC} calculation:

| i | R_{thi} (K/W) | t_i (s) |
|---|-----------------|-----------|
| 1 | 0.3073 | 0.0055 |
| 2 | 0.3533 | 0.0092 |
| 3 | 0.0887 | 0.0007 |
| 4 | 0.1008 | 0.0399 |